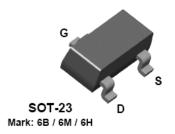


February 2009

2N5484/5485/5486 MMBF5484/5485/5486





NOTE: Source & Drain are interchangeable

N-Channel RF Amplifier

This device is designed primarily for electronic switching applications such as low On Resistance analog switching. Sourced from Process 50.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{DG}	Drain-Gate Voltage	25	V
V _{GS}	Gate-Source Voltage	- 25	V
I _{GF}	Forward Gate Current	10	mA
T _J ,T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

<u>NOTES:</u>
1) These ratings are based on a maximum junction temperature of 150 degrees C.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max		Units
		2N5484-5486	*MMBF5484-5486	
P _D	Total Device Dissipation	350	225	mW
	Derate above 25°C	2.8	1.8	mW/°C
R _e Jc	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

²⁾ These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

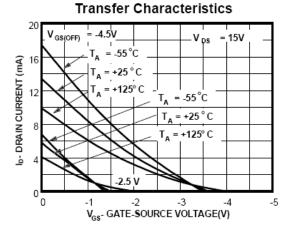
N-Channel RF Amplifier (continued)

Cumbal	Parameter	Test Conditions	N1:	T	Mass	Units
Symbol	Parameter	rest Conditions	Min	Тур	Max	Units
OFF CHAI	RACTERISTICS					
V _{(BR)GSS}	Gate-Source Breakdown Voltage	I _G = - 1.0 μA, V _{DS} = 0	- 25			V
I _{GSS}	Gate Reverse Current	V _{GS} = - 20 V, V _{DS} = 0			- 1.0	nA
V _{GS(off)}	Gate-Source Cutoff Voltage	V _{GS} = - 20 V, V _{DS} = 0, T _A = 100°C V _{DS} = 15 V, I _D = 10 nA 5484	- 0.3		- 0.2	μA
v G5(011)	outo-source outon voltage	5485	- 0.5		- 4.0	V
ON CHAR	ACTERISTICS	5486	- 2.0		- 6.0	V
I _{DSS}	Zero-Gate Voltage Drain Current*	V _{DS} = 15 V, V _{GS} = 0 5484	1.0		5.0	mA
-500		5485	4.0		10	mA
		5486	8.0		20	mA
SMALL SI	GNAL CHARACTERISTICS Forward Transfer Conductance	V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz	2000		0000	
		5484 5485	3000 3500		6000 7000	μmho μmho
		5486	4000		8000	μmho
Re(yis)	Input Conductance	V _{DS} = 15 V, V _{GS} = 0, f = 100 MHz 5484			100	μmho
		V _{DS} = 15 V, V _{GS} = 0, f = 400 MHz 5485 / 5486			1000	μmho
gos	Output Conductance	$V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}$			50	
		5484 5485			60	μmho μmho
		5486			75	μmho
Re _(yos)	Output Conductance	V _{DS} = 15 V, V _{GS} = 0, f = 100 MHz 5484			75	μmho
		V _{DS} = 15 V, V _{GS} = 0, f = 400 MHz 5485 / 5486			100	μmho
Re(yfs)	Forward Transconductance	V _{DS} = 15 V, V _{GS} = 0, f = 100 MHz			100	μππο
		5484 V _{DS} = 15 V, V _{GS} = 0, f = 400 MHz	2500			μmho
		5485	3000			μmho
		5486	3500			μmho
Ciss	Input Capacitance	$V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ MHz}$			5.0	pF
Crss	Reverse Transfer Capacitance	V _{DS} = 15 V, V _{GS} = 0, f = 1.0 MHz			1.0	pF
Coss	Output Capacitance	V _{DS} = 15 V, V _{GS} = 0, f = 1.0 MHz			2.0	pF
NF	Noise Figure	V_{DS} = 15 V, R_{G} = 1.0 k Ω , f = 100 MHz 5484			3.0	dB
		V_{DS} = 15 V, R_{G} = 1.0 k Ω , f = 400 MHz 5484		4.0		dB
		V_{DS} = 15 V , R_{G} = 1.0 k Ω , f = 100 MHz 5485 / 5486			2.0	dB
		V_{DS} = 15 V, R_{G} = 1.0 kΩ, f = 400 MHz 5485 / 5486			4.0	dB

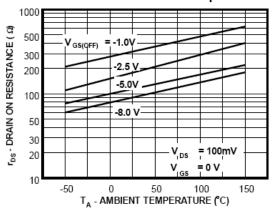
N-Channel RF Amplifier

(continued)

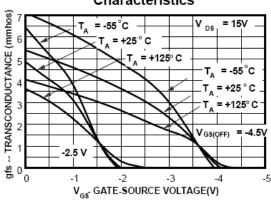
Typical Characteristics



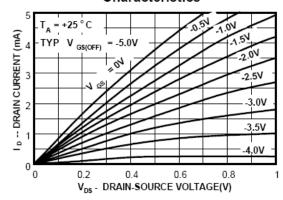
Channel Resistance vs Temperature



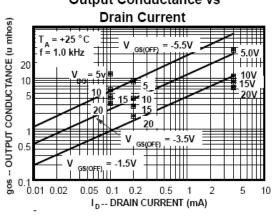
Transconductance Characteristics



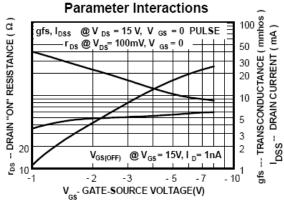
Common Drain-Source Characteristics



Output Conductance vs

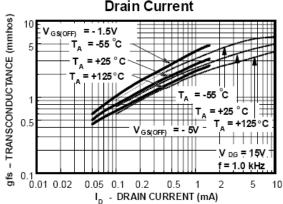


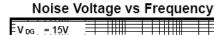
Transconductance

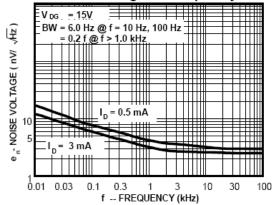


Typical Characteristics (continued)

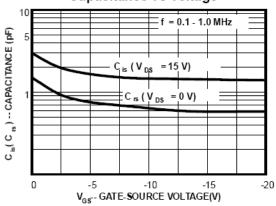
Transconductance vs **Drain Current**



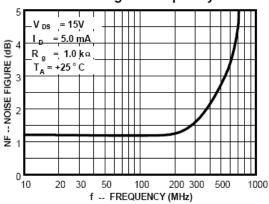




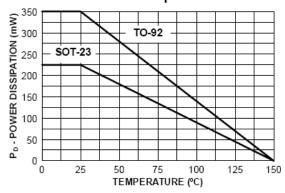
Capacitance vs Voltage



Noise Figure Frequency



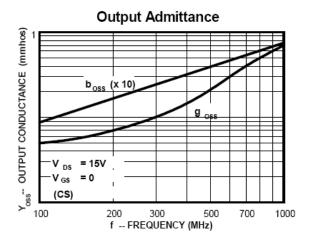
Power Dissipation vs. **Ambient Temperature**

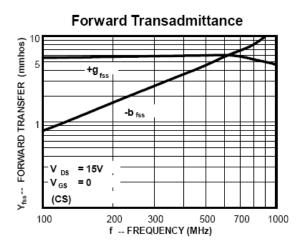


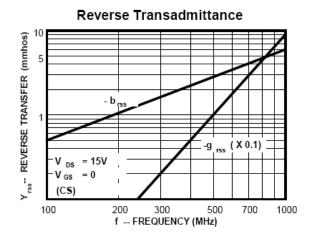
N-Channel RF Amplifier

(continued)

Common Source Characteristics



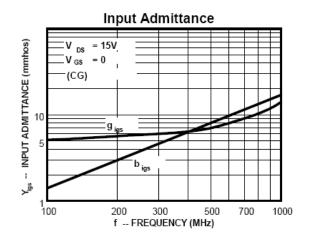


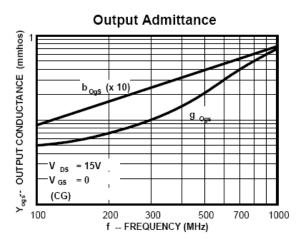


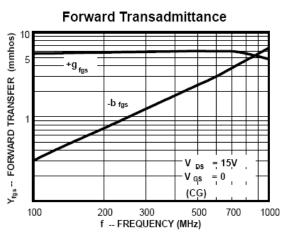
N-Channel RF Amplifier

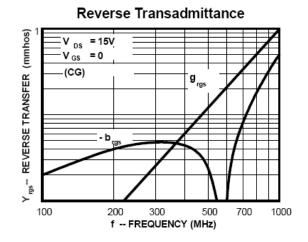
(continued)

Common Gate Characteristics













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